

View Online at <https://aerobasegroup.com/nsn/5961-00-238-6871>

Inclosure Material:

Metal

Overall Length:

0.185 inches

Terminal Length:

0.500 inches

Overall Diameter:

Between 0.335 inches and 0.370 inches

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

-60.0 breakdown voltage, collector-to-base, emitter open all transistor and -45.0 breakdown voltage, collector-to-emitter, base open all transistor and -6.0 breakdown voltage, emitter-to-base, collector open all transistor

Current Rating Per Characteristic:

-10.00 nanoamperes zero-gate-voltage source current preset all transistor and -2.00 nanoamperes zero-gate-voltage source current major all transistor

Power Rating Per Characteristic:

0.6 watts small-signal input power, common-emitter outside diameter all transistor

Capacitance Rating In Picofarads:

6.0 all transistor

Transfer Ratio:

300.0 static forward current transfer ratio, common-emitter all transistor

Maximum Operating Temperature Per Measurement Point:

200.0 degrees celsius ambient air

Special Features:

All transistor junction pattern arrangement: pnp

Terminal Type And Quantity:

6 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

A110a0